

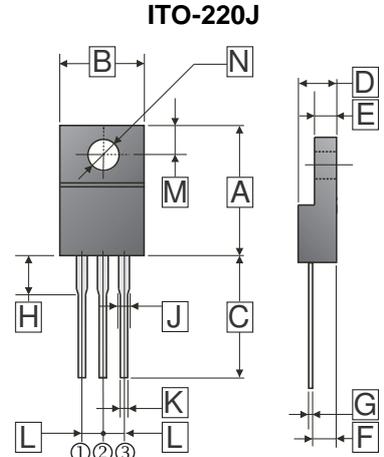
RoHS Compliant Product
A suffix of "-C" specifies halogen free

FEATURES

- Metal Silicon Junction and Majority Carrier Conduction
- Low Power Loss
- High Efficiency
- High Current Capability

MECHANICAL DATA

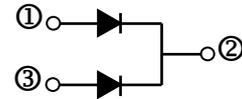
- Case: ITO-220J Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: As Marked
- Mounting Position: Any



ORDER INFORMATION

Part Number	Type
MBR30L60F	Lead (Pb)-free
MBR30L60F-C	Lead (Pb)-free and Halogen-free

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.50	15.50	H	3.80 TYP.	
B	9.50	10.50	J	1.30 REF.	
C	13.20 REF.		K	0.30	0.90
D	4.24	4.84	L	2.54 REF.	
E	2.52	3.20	M	2.70 REF.	
F	2.50	2.90	N	φ 3.50 REF.	
G	0.47	0.75			



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, de-rate current by 20%.)

Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	60	V
Working Peak Reverse Voltage	V_{RSM}	60	V
Maximum DC Blocking Voltage	V_{DC}	60	V
Maximum Average Forward Rectified Current	Per Leg	15	A
	Per Device	30	
Peak Forward Surge Current, 8.3ms single half sine-wave Superimposed on rated load (JEDEC method)	I_{FSM}	200	A
Maximum Instantaneous Forward Voltage @ $I_F=15A$	$T_J=25^\circ C$	0.75	V
	$T_J=125^\circ C$	0.65	
Maximum DC Reverse Current @ Rated DC Blocking Voltage ²	$T_J=25^\circ C$	0.2	mA
	$T_J=75^\circ C$	10	
Typical Junction Capacitance ¹	C_J	625	pF
Single Pulse Reverse Avalanche Energy	$T_J=25^\circ C, L=15mH$	270	mJ
	$T_J=100^\circ C, L=15mH$	67.5	
Single Pulse Reverse Avalanche Current	$T_J=25^\circ C, L=15mH$	6	A
	$T_J=100^\circ C, L=15mH$	3	
Typical Thermal Resistance Junction-Case	$R_{\theta JC}$	4	°C/W
Operating Junction & Storage Temperature Range	T_J, T_{STG}	-55~150	°C

Notes:

1. Measured at 1MHz and applied reverse voltage of 5V D.C.
2. Pulse Test: Pulse Width=300µs, Duty Cycle ≤2%.

CHARACTERISTIC CURVES

